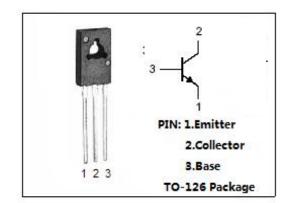


isc Silicon NPN Power Transistor

MJE520

DESCRIPTION

- High Collector Current-I_C= 3.0A
- · High Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 30V(Min)
- Good Linearity of hFE
- Low Saturation Voltage
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

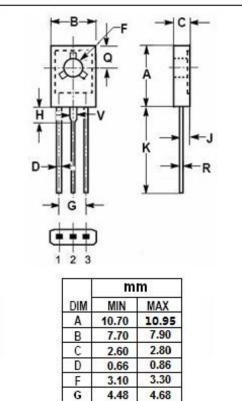


APPLICATIONS

Designed for power amplifier applications

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	4	V
lc	Collector Current-Continuous	3	А
I _{CP}	Collector Current-Pulse	7	Α
Pc	Collector Power Dissipation @ T _C =25°C	25	W
TJ	Junction Temperature	150	$^{\circ}$ C
T _{stg}	Storage Temperature Range	-65~150	$^{\circ}$



2.00

1.35

15.30

3.70

0.40

1.17

K

Q

R

2.20

1.55

16.30

3.90

0.60

1.37

isc website: www.iscsemi.com

¹ isc & iscsemi is registered trademark



isc Silicon NPN Power Transistor

MJE520

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 100 μ A ; I _E = 0	30			V
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 100mA	30			V
V _{(BR)EBO}	Emitter-Base Breakdown Vltage	I _E = 100 μ A ; I _C = 0	4			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 500mA; I _B = 50mA			0.5	V
Ісво	Collector Cutoff Current	V _{CB} = 50V; I _E = 0			10	μА
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4V; I _C = 0			10	μА
h _{FE-1}	DC Current Gain	I _C = 1 A; V _{CE} = 1 V	20			
f⊤	Current-Gain—Bandwidth Product	I _C = 50mA; V _{CE} = 10V	30			MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V,f _{test} = 1MHz		20		pF



ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications. ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

isc website: www.iscsemi.com

² isc & iscsemi is registered trademark